

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Report No: CCISE160306201

FCC REPORT

(GSM & WCDMA)

Applicant: SHENZHEN COOTEL FONE TECHNOLOGY CO., LTD

Address of Applicant: 5D-F, Buliding R1-A, MCM, Hi-tech Park, Nanshan District,

Shenzhen

Equipment Under Test (EUT)

Product Name: smart phone

Model No.: S32

FCC ID: 2AHS2-CTF-S32

FCC CFR Title 47 Part 2

Applicable standards: FCC CFR Title 47 Part 22 Subpart H

FCC CFR Title 47 Part 24 Subpart E

Date of sample receipt: 24 Mar., 2016

Date of Test: 24 Mar., to 11 Apr., 2016

Date of report issued: 12 Apr., 2016

Test Result: PASS*

* In the configuration tested, the EUT complied with the standards specified above.

Authorized Signature:



Bruce Zhang Laboratory Manager

This report details the results of the testing carried out on one sample. The results contained in this test report do not relate to other samples of the same product and does not permit the use of the CCIS product certification mark. The manufacturer should ensure that all products in series production are in conformity with the product sample detailed in this report.

This report may only be reproduced and distributed in full. If the product in this report is used in any configuration other than that detailed in the report, the manufacturer must ensure the new system complies with all relevant standards.

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2. Version

Version No.	Date	Description
00	12 Apr., 2016	Original

Steven Giu Test Engineer Tested by: Date: 12 Apr., 2016

Reviewed by: Date: 12 Apr., 2016

Project Engineer



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4. Test Summary

Test Item	Section in CFR 47	Result
RF Exposure (SAR)	Part 1.1307 Part 2.1093	Pass (Please refer to SAR Report)
RF Output Power	Part 2.1046 Part 22.913 (a)(2) Part 24.232 (c)	Pass
Peak-to-Average Power Ratio	Part 24.232 (d)	Pass
Modulation Characteristics	Part 2.1047	Pass
99% & -26 dB Occupied Bandwidth	Part 2.1049 Part 22.917(b) Part 24.238(b)	Pass
Spurious Emissions at Antenna Terminal	Part 2.1051 Part 22.917 (a) Part 24.238 (a)	Pass
Field Strength of Spurious Radiation	Part 2.1053 Part 22.917 (a) Part 24.238 (a)	Pass
Out of band emission, Band Edge	Part 22.917 (a) Part 24.238 (a)	Pass
Frequency stability vs. temperature	Part 2.1055(a)(1)(b)	Pass
Frequency stability vs. voltage	Part 2.1055(d)(1)(2)	Pass

Pass: The EUT complies with the essential requirements in the standard.





5. General Information

5.1 Client Information

Applicant:	SHENZHEN COOTEL FONE TECHNOLOGY CO., LTD
Address of Applicant:	5D-F, Buliding R1-A, MCM, Hi-tech Park, Nanshan District, Shenzhen
Manufacturer	SHENZHEN COOTEL FONE TECHNOLOGY CO., LTD
Address of Manufacturer:	5D-F, Buliding R1-A, MCM, Hi-tech Park, Nanshan District, Shenzhen
Factory:	Dongguan Changhua Electronic Technology Co., Ltd.
Address of Factory:	2th floor, 1st industrial building of Dongxinwei, west Fuxing Road, Xiagang Community, Changan Town,Dongguan City, Guangdong Province

5.2 General Description of E.U.T.

Product Name:	smart phone
Model No.:	S32
Operation Frequency range:	GSM 850: 824.20MHz-848.80MHz
	PCS1900: 1850.20MHz-1909.80MHz
	WCDMA Band V: 826.4MHz-846.6MHz
	WCDMA Band II: 1852.4 MHz -1907.6 MHz
Modulation type:	GSM/GPRS:GMSK, UMTS:QPSK, EGPRS: 8PSK
Antenna type:	Internal Antenna
Antenna gain:	GSM 850: 0.56 dBi
	PCS 1900: 1.20 dBi
	WCDMA Band V: 0.56 dBi
	WCDMA Band II: 1.60 dBi
Power supply:	Rechargeable Li-ion Battery DC3.8V-2910mAh
AC adapter:	Model: U0D2F0A050150
	Input: AC100-240V 50/60Hz 250mA
	Output: DC 5.0V, 1.5A





Operation Frequency List:				
GSI	GSM 850		1900	
Channel:	Frequency (MHz)	Channel:	Frequency (MHz)	
128	824.20	512	1850.20	
129	824.40	513	1850.40	
189	836.40	660	1879.80	
190	836.60	661	1880.00	
191	836.80	662	1880.20	
250	848.60	809	1909.60	
251	848.80	810	1909.80	
WCDM	A Band V	WCDMA Band II		
Channel:	Frequency (MHz)	Channel:	Frequency (MHz)	
4132	826.40	9262	1852.40	
4133	826.60	9263	1852.60	
4182	836.40	9399	1879.80	
4183	836.60	9400	1880.00	
4184	836.80	9401	1880.20	
4232	846.40	9537	1907.40	
4233	846.60	9538	1907.60	



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Regards to the operating frequency range over 10 MHz, the Lowest frequency, the middle frequency, and the highest frequency of channel were selected to perform the test, and the selected channel see below:

GSM850			PCS1900			
Channel		Frequency(MHz)	Channel		Frequency(MHz)	
Lowest channel	128	824.20	Lowest channel	512	1850.20	
Middle channel	190	836.60	Middle channel	661	1880.00	
Highest channel	251	848.80	Highest channel 810		1909.80	
,	NCDMA Band	d V	WCDMA Band II			
Channe	el	Frequency(MHz)	c) Channel Frequency(Frequency(MHz)	
Lowest channel	4132	826.40	Lowest channel 9262		1852.40	
Middle channel	4183	836.60	Middle channel 9400		1880.00	
Highest channel	4233	846.60	Highest channel	9538	1907.60	



5.3 Test modes

Voice mode	Keep the EUT in voice mode on GSM 850 and PCS 1900 respectively.
Data mode (GPRS)	Keep the EUT in GPRS mode on GSM 850 and PCS 1900 respectively.
Data mode (EGPRS)	Keep the EUT in EGPRS mode on GSM 850 and PCS 1900 respectively.
Voice mode (AMR 12.2 kbps)	Keep the EUT in voice mode on WCDMA Band II and V respectively.
Data mode (RMC 12.2kbps)	Keep the EUT in RMC on WCDMA Band II and V respectively.
Data mode (HSDPA Subtest 1~4)	Keep the EUT in HSDPA mode on WCDMA Band II and V respectively.
Data mode (HSUPA Subtest 1~5)	Keep the EUT in HSUPA mode on WCDMA Band II and V respectively.
Remark:	Just the worst case mode shown in report.

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5.4 Related Submittal(s) / Grant (s)

This submittal(s) (test report) is filing to comply with Section Part 22 subpart H and Part 24 subpart E of the FCC CFR 47 Rules.

5.5 Test Methodology

Both conducted and radiated testing were performed according to the procedures document on TIA/EIA 603 and FCC CFR 47.1046, 2.1047, 2.1049, 2.1051, 2.1053, 2.1055 and 2.1057

5.6 Laboratory Facility

The test facility is recognized, certified, or accredited by the following organizations:

• FCC - Registration No.: 817957

Shenzhen Zhongjian Nanfang Testing Co., Ltd. EMC Laboratory has been registered and fully described in a report filed with the (FCC) Federal Communications Commission. The acceptance letter from the FCC is maintained in out files. Registration 817957, February 27, 2012.

• IC - Registration No.: 10106A-1

The 3m Semi-anechoic chamber of Shenzhen Zhongjian Nanfang Testing Co., Ltd. has been Registered by Certification and Engineering Bureau of Industry Canada for radio equipment testing with Registration No.: 10106A-1.

CNAS - Registration No.: CNAS L6048

Shenzhen Zhongjian Nanfang Testing Co., Ltd. is accredited to ISO/IEC 17025:2005 General Requirements for the Competence of Testing and Calibration laboratories for the competence of testing. The Registration No. is CNAS L6048.

5.7 Laboratory Location

Shenzhen Zhongjian Nanfang Testing Co., Ltd.

Address: No. B-C, 1/F., Building 2, Laodong No.2 Industrial Park, Xixiang Road,

Bao'an District, Shenzhen, Guangdong, China

Tel: +86-755-23118282 Fax: +86-755-23116366

5.8 Description of Support Units

N/A





5.9 Test Instruments list

Radiated Emission:						
Item	Test Equipment	Manufacturer	Model No.	Inventory No.	Cal. Date (mm-dd-yy)	Cal. Due date (mm-dd-yy)
1	3m Semi- Anechoic Chamber	SAEMC	9(L)*6(W)* 6(H)	CCIS0001	08-23-2014	08-22-2017
2	BiConiLog Antenna	SCHWARZBECK MESS-ELEKTRONIK	VULB9163	CCIS0005	03-25-2016	03-25-2017
3	Double -ridged waveguide horn	SCHWARZBECK MESS-ELEKTRONIK	BBHA9120D	CCIS0006	03-25-2016	03-25-2017
4	EMI Test Software	AUDIX	E3	N/A	N/A	N/A
5	Amplifier (10kHz-1.3GHz)	HP	8447D	CCIS0003	04-01-2016	03-31-2017
6	Amplifier (1GHz-18GHz)	Compliance Direction Systems Inc.	PAP-1G18	CCIS0011	04-01-2016	03-31-2017
7	Pre-amplifier (18-26GHz)	Rohde & Schwarz	AFS33-18002 650-30-8P-44	GTS218	04-01-2016	03-31-2017
8	Horn Antenna	ETS-LINDGREN	3160	GTS217	04-01-2016	03-31-2017
9	Printer	HP	HP LaserJet P1007	N/A	N/A	N/A
10	Positioning Controller	UC	UC3000	CCIS0015	N/A	N/A
11	Spectrum analyzer 9k-30GHz	Rohde & Schwarz	FSP 30	CCIS0023	03-28-2016	03-28-2017
12	EMI Test Receiver	Rohde & Schwarz	ESPI	CCIS0022	03-28-2016	03-28-2017
13	Loop antenna	Laplace instrument	RF300	EMC0701	04-01-2016	03-31-2017
14	Universal radio communication tester	Rhode & Schwarz	CMU200	CCIS0069	03-28-2016	03-28-2017
15	Signal Analyzer	Rohde & Schwarz	FSIQ3	CCIS0088	04-08-2015	04-08-2016
16	DC Power Supply	Shenzhen XinNuoEr Technologies Co., Ltd.	WYK-10020K	CCIS0201	10-31-2015	10-30-2016
17	Temperature Humidity Chamber	Fo Shan Heng Pu Electronics Co., Ltd.	HPGDS-500	CCIS0240	11-18-2015	11-27-2016



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6. System test configuration

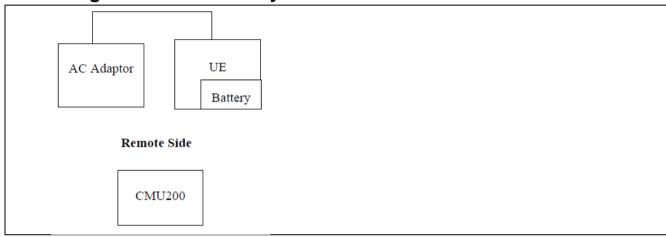
6.1 EUT Configuration

The EUT configuration for testing is installed on RF field strength measurement to meet the commission's requirement and operating in a manner which intends to maximize its emission characteristics in a continuous normal application.

6.2 EUT Exercise

The EUT (Transmitter) was operated in the engineering mode to fix the Tx frequency which was for the purpose of the measurements.

6.3 Configuration of Tested System



6.4 Description of Test Modes

The EUT has been tested under operating condition.

EUT staying in continuous transmitting mode. Channel Low, Mid and High for each type band with rated data rate were chosen for full testing.

The field strength of spurious radiation emission was measured as EUT stand-up position (H mode) and lie down position (E1, E2 mode) for three modes (GSM850, PCS1900, WCDMA Band V and WCDMA Band II) with power adaptor, earphone and Data cable. The worst-case H mode for GSM850, PCS1900, WCDMA Band V and WCDMA Band II.





6.5 Conducted Output Power

Test Requirement:	FCC part 22.913(a), FCC part 24.232(b)			
Test Method:	FCC part 2.1046			
Limit:	GSM 850: 7W PCS 1900: 2W WCDMA Band V: 7W WCDMA Band II: 2W			
Test setup:	EUT ATT Communication Tester Note: Measurement setup for testing on Antenna connector			
Test Procedure:	The transmitter output was connected to a calibrated attenuator, the other end of which was connected to the simulated station. Transmitter output power was read off in dBm.			
Test Instruments:	Refer to section 5.8 for details			
Test mode:	Refer to section 5.3 for details			
Test results:	Passed			

Measurement Data





	Bur	st Average power (d	Bm)	
EUT Mode	128	190	251	Limit(dBm)
	824.20MHz	836.60MHz	848.80MHz	
GSM 850	33.19	33.20	33.23	
GPRS 850 (1 Uplink slot)	33.01	33.06	33.08	
GPRS 850 (2 Uplink slot)	31.70	31.73	31.53	
GPRS 850 (3 Uplink slot)	30.31	30.43	30.62	
GPRS 850 (4 Uplink slot)	29.15	29.44	29.29	38.45
EGPRS 850 (1 Uplink slot)	27.38	27.31	27.24	
EGPRS 850 (2 Uplink slot)	25.78	25.77	25.67	
EGPRS 850 (3 Uplink slot)	24.66	24.53	23.72	
EGPRS 850 (4 Uplink slot)	23.41	23.36	23.27	
	Bur			
EUT Mode	512	661	810	Limit(dBm)
	1850.20MHz	1880.00MHz	1909.80MHz	
PCS 1900	30.36	30.07	30.07	
GPRS 1900 (1 Uplink slot)	30.26	30.13	30.13	
GPRS 1900 (2 Uplink slot)	28.64	28.44	28.34	
GPRS 1900 (3 Uplink slot)	27.17	27.45	27.27	
GPRS 1900 (4 Uplink slot)	25.86	25.83	26.05	33.00
EGPRS 1900 (1 Uplink slot)	26.13	26.17	26.14	
EGPRS 1900 (2 Uplink slot)	24.45	24.45	24.48	
EGPRS 1900 (3 Uplink slot)	22.57	23.34	23.33	
EGPRS 1900 (4 Uplink slot)	22.23	22.24	21.15	

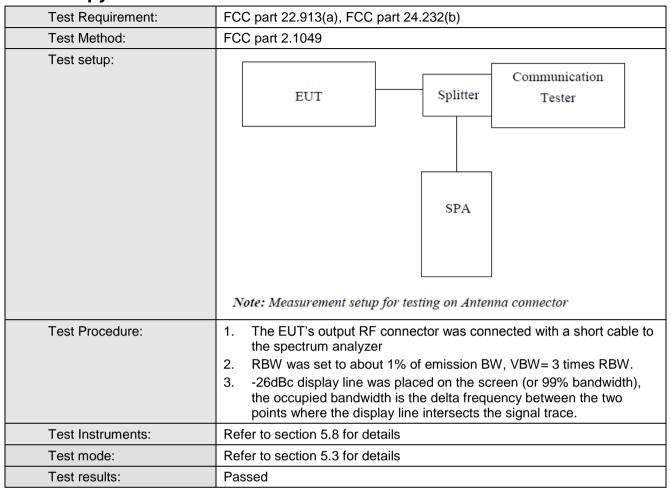




		Burst	Average power (di	3m)	
EUT Mode		4132	4183	4233	Limit(dBm)
		826.40MHz	836.60MHz	846.60MHz	
	Subtest 1	23.06	23.07	22.94	
UMTS 850	Subtest 2	23.20	23.23	23.25	
HSDPA	Subtest 3	21.61	21.59	21.66	
	Subtest 4	21.34	21.33	21.44	
	Subtest 1	22.56	22.59	22.56	
	Subtest 2	23.28	23.14	23.16	38.45
UMTS 850 HSUPA	Subtest 3	22.25	22.17	22.21	
110017	Subtest 4	23.31	23.20	23.21	
	Subtest 5	22.35	22.25	22.38	
UMTS 850 RMC	12.2kbps	24.24	24.31	24.29	
UMTS 850 AMR	12.2kbps	24.05	24.12	24.11	
		Burst			
EUT Mo	ode	9262	9400	9538	Limit(dBm)
		1852.40MHz	1880.00MHz	1907.60MHz	
	Subtest 1	23.21	23.20	23.06	
UMTS 1900	Subtest 2	21.62	21.62	21.70	
HSDPA	Subtest 3	21.22	21.50	21.30	
	Subtest 4	21.87	21.74	21.22	
	Subtest 1	22.60	22.64	22.47	
LIMTO 4000	Subtest 2	23.31	23.29	23.02	33.00
UMTS 1900 HSUPA	Subtest 3	22.05	22.30	22.04	
	Subtest 4	23.42	23.27	23.07	
	Subtest 5	22.31	22.32	22.25	
UMTS 1900 RMC	12.2kbps	24.36	24.38	24.22	



6.6 Occupy Bandwidth



Measurement Data





EUT Mode	Channel	Frequency (MHz)	99% Occupy bandwidth (kHz)	-26dB bandwidth (kHz)
GSM 850	128	824.2	248	318
	190	836.6	244	312
	251	848.8	244	316
EGPRS850	128	824.2	242	304
	190	836.6	246	312
	251	848.8	240	302
PCS 1900	512	1850.2	242	316
	661	1880.0	246	318
	810	1909.8	244	316
EGPRS1900	512	1850.2	254	316
	661	1880.0	248	310
	810	1909.8	244	306
WCDMA BAND V 12.2k RMC	4132	826.4	4160	4720
	4183	836.6	4140	4720
	4233	846.6	4160	4760
WCDMA BAND II 12.2k RMC	9262	1852.4	4320	4980
	9400	1880.0	4200	4800
	9538	1907.6	4200	4780

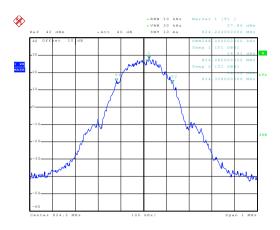
Note: GSM & GPRS use the same modulation technical (GMSK), and with the same channels, so the 99% OBW and the -26dB of GPRS not performed.

Test plot as follows:



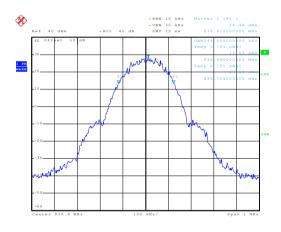
99% Occupy bandwidth

GSM850



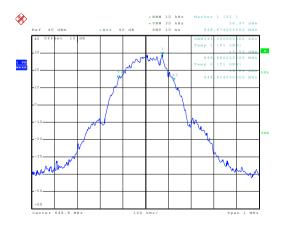
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Lowest channel



Date: 21.MAR.2016 09:50:16

Middle channel



Date: 21.MAR.2016 09:50:34

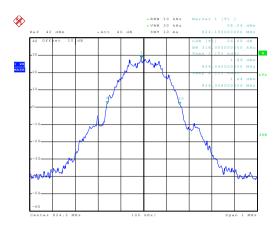
Highest channel

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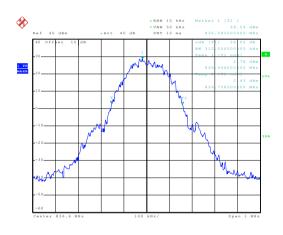
26dB Emission Bandwidth

GSM850



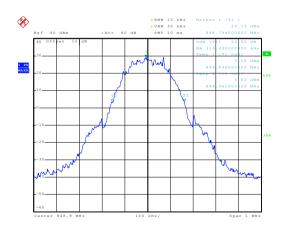
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Lowest channel



Date: 21.MAR.2016 09:50:06

Middle channel



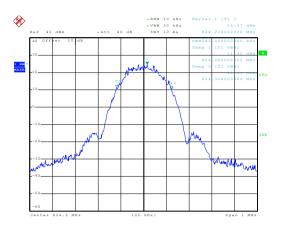
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Highest channel



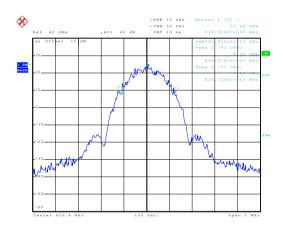
99% Occupy bandwidth

EGPRS850



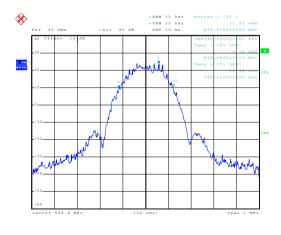
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Lowest channel



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Middle channel



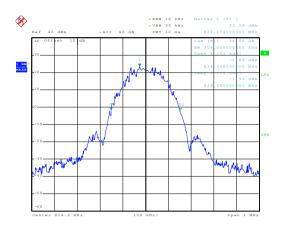
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Highest channel



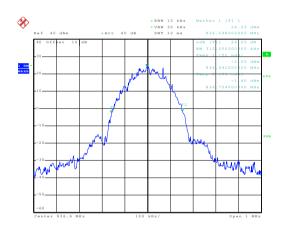
26dB Emission Bandwidth

EGPRS850



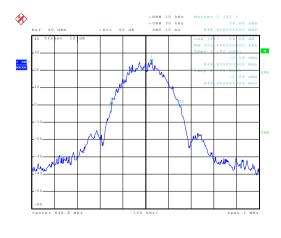
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Lowest channel



Date: 5.APR.2016 21:41:39

Middle channel



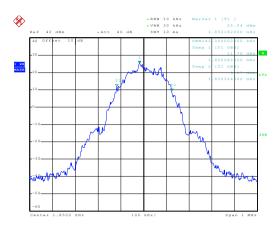
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Highest channel



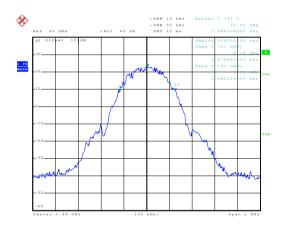
99% Occupy bandwidth

PCS 1900



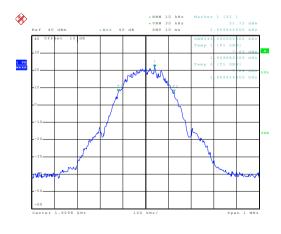
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Lowest channel



Date: 21.MAR.2016 09:57:47

Middle channel



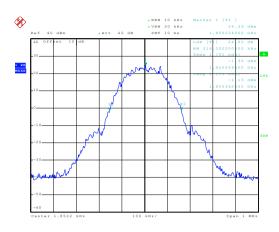
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Highest channel



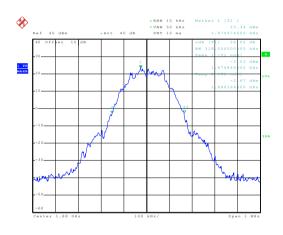
26dB Emission Bandwidth

PCS 1900



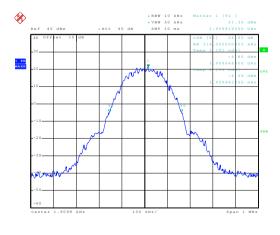
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Lowest channel



Date: 21.MAR.2016 09:58:01

Middle channel



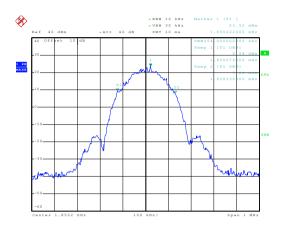
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Highest channel



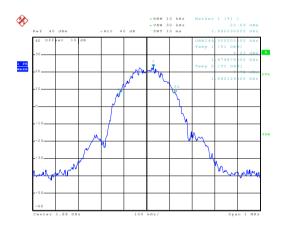
99% Occupy bandwidth

EGPRS 1900



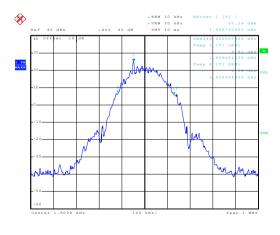
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Lowest channel



Date: 5.APR.2016 21:56:46

Middle channel



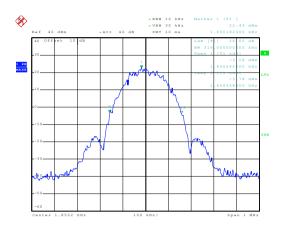
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Highest channel



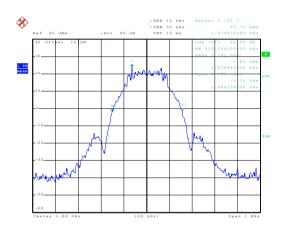
26dB Emission Bandwidth

EGPRS 1900



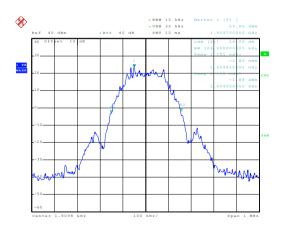
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Lowest channel



Date: 5.APR.2016 21:56:31

Middle channel



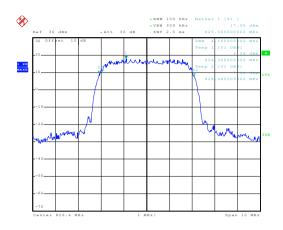
Date: 5.APR.2016 21:57:30

Highest channel



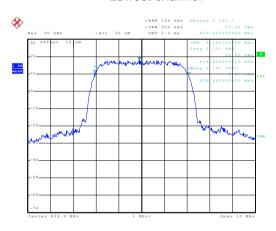
99% Occupy bandwidth

UMTS 850 12.2k RMC



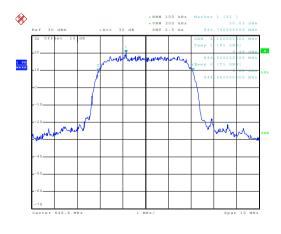
Date: 21.MAR.2016 09:28:39

Lowest channel



Date: 21.MAR.2016 09:28:30

Middle channel



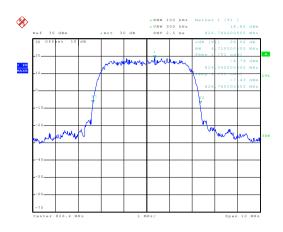
Date: 21.MAR.2016 09:28:05

Highest channel



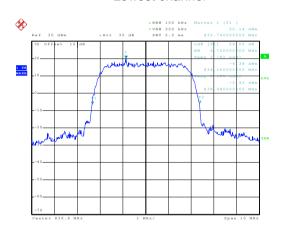
26dB Emission Bandwidth

UMTS 850 12.2k RMC



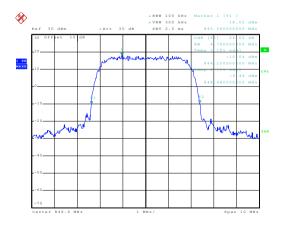
Date: 21.MAR.2016 09:28:47

Lowest channel



Date: 21.MAR.2016 09:28:22

Middle channel



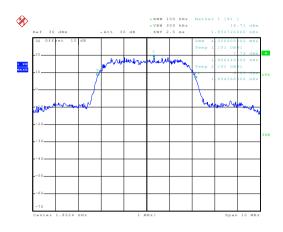
Date: 21.MAR.2016 09:28:12

Highest channel



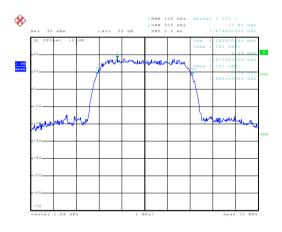
99% Occupy bandwidth

UMTS 1900 12.2k RMC



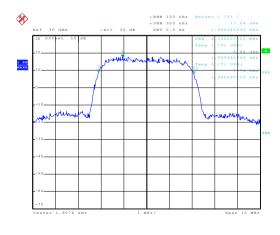
Date: 21.MAR.2016 09:29:40

Lowest channel



Date: 21.MAR.2016 09:29:55

Middle channel



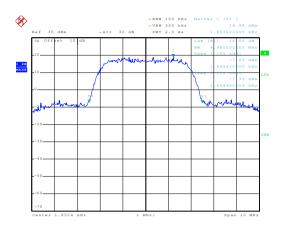
Date: 21.MAR.2016 09:30:20

Highest channel



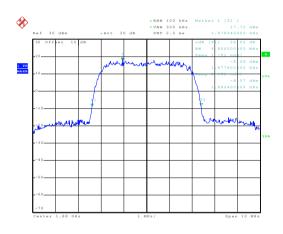
26dB Emission Bandwidth

UMTS 1900 12.2k RMC



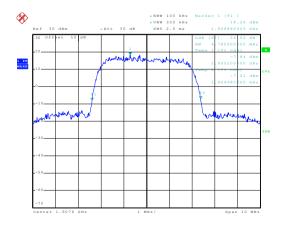
Date: 21.MAR.2016 09:29:32

Lowest channel



Date: 21.MAR.2016 09:30:02

Middle channel



Date: 21.MAR.2016 09:30:13

Highest channel



6.7 Peak-to-Average Power Ratio

Test Requirement:	FCC part 24.232(d)		
Limit:	The peak-to-average ratio (PAR) of the transmission may not exceed 13 dB.		
Test setup:	EUT Splitter Communication Tester ATT SPA Note: Measurement setup for testing on Antenna connector		
Test Procedure:	 The RF output of the transceiver was connected to a spectrum analyzer through appropriate attenuation. Set the CCDF option in spectrum analyzer, RBW ≥ OBW, Set the EUT working in highest power level, measured and recorded the 0.1% as PAPR level. Repeat step 1~3 at other frequency and modulations. 		
Test Instruments:	Refer to section 5.8 for details		
Test mode:	Refer to section 5.3 for details		
Test results:	Passed		

Measurement Data (worst case)

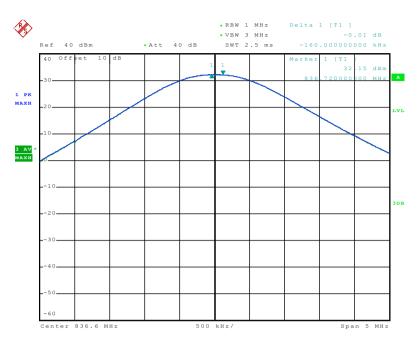
Modulation	Test channel	PAPR
GSM 850	190	0.01
EGPRS 850	190	0.04
PCS 1900	661	0.00
EGPRS 1900	661	0.11
UMTS 850 RMC	4183	2.84
UMTS 1900 RMC	9400	2.36



Test plots as below:

Middle channel

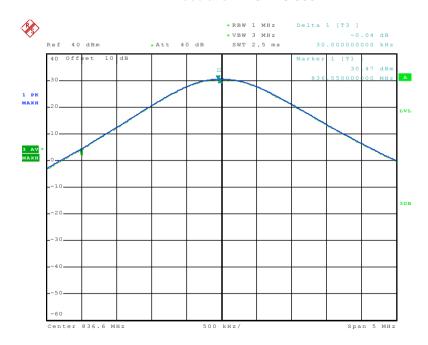
Modulation: GSM 850



Date: 21.MAR.2016 10:09:50

Middle channel

Modulation: EGPRS 850

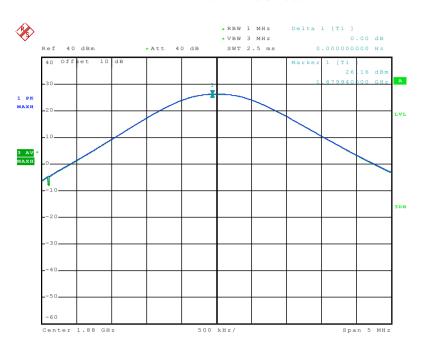


Date: 5.APR.2016 21:50:40



Middle channel

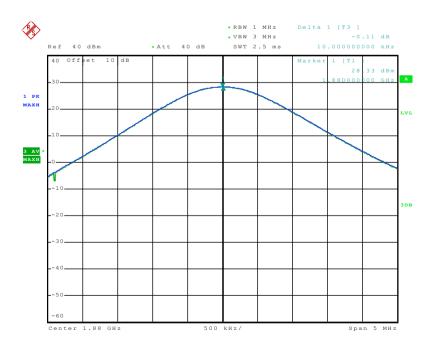
Modulation: PCS 1900



Date: 21.MAR.2016 10:08:52

Middle channel

Modulation: EGPRS 1900

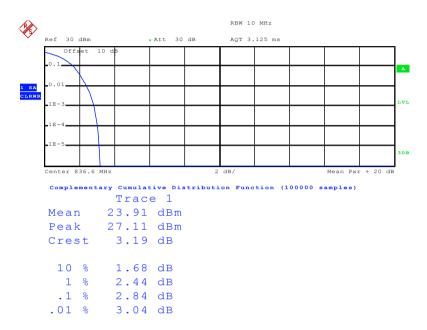


Date: 5.APR.2016 21:53:54



Middle channel

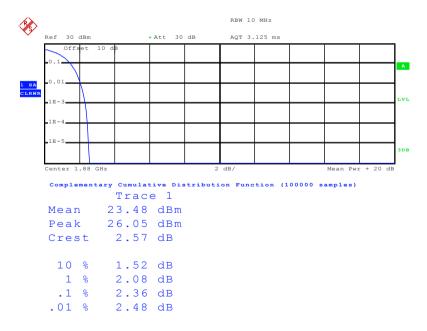
Modulation: WCDMA Band V RMC



Date: 21.MAR.2016 09:35:06

Middle channel

Modulation: WCDMA BAND II RMC



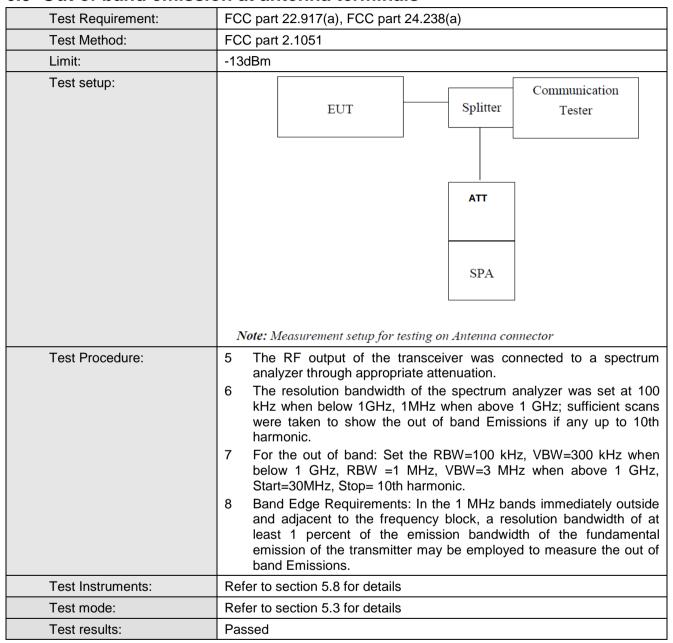
Date: 21.MAR.2016 09:34:45



6.8 Modulation Characteristic

According to FCC § 2.1047(d), Part 22H & 24E there is no specific requirement for digital modulation, therefore modulation characteristic is not presented.

6.9 Out of band emission at antenna terminals



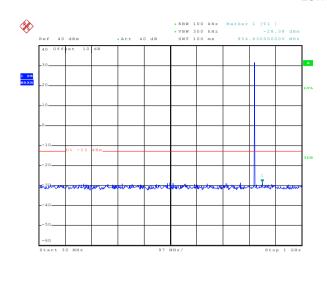
Test plots as follows:

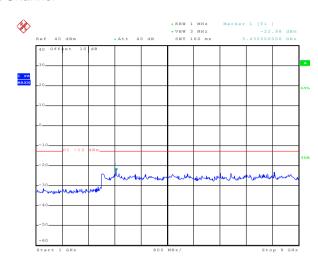


Spurious emission

GSM 850

Lowest Channel





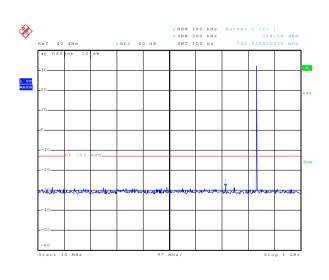
Date: 21.MAR.2016 09:48:43

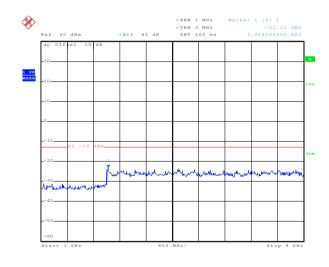
30MHz~1GHz

Date: 21.MAR.2016 09:48:55 1GHz~9GHz

Date: 21.MAR.2016 09:49:02

Middle channel





Date: 21.MAR.2016 09:48:28

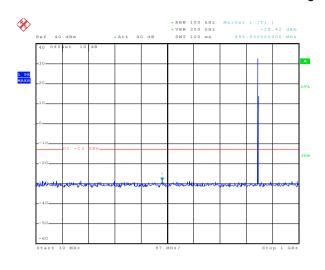
30MHz~1GHz

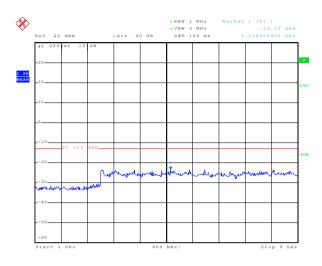
1GHz~9GHz





Highest Channel



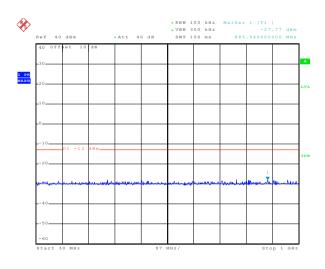


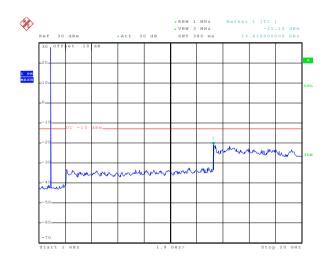
Date: 21.MAR.2016 09:48:08

30MHz~1GHz

PCS 1900

Lowest Channel





Date: 6.APR.2016 23:07:08

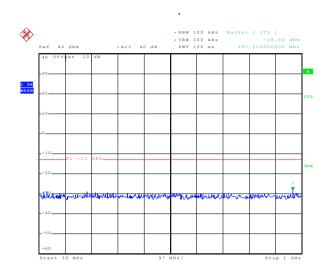
30MHz~1GHz

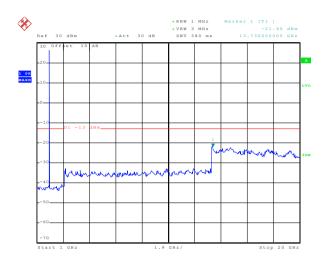
1GHz~20GHz

Date: 21.MAR.2016 10:07:23



Middle Channel





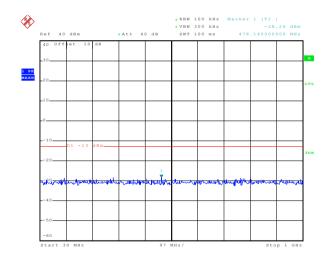
Date: 21.MAR.2016 10:01:06

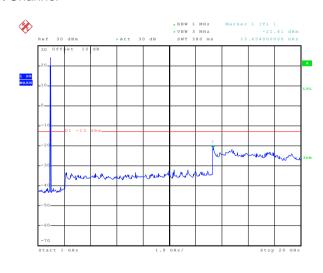
30MHz~1GHz

1GHz~20GHz

Highest Channel

Date: 21.MAR.2016 10:06:29





Date: 21.MAR.2016 10:01:18

30MHz~1GHz

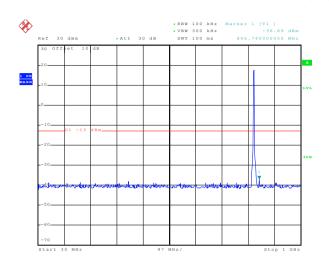
1GHz~20GHz

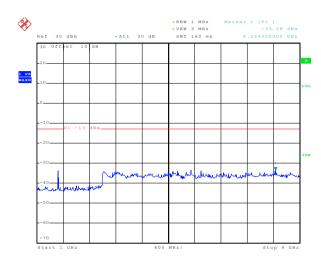
Date: 21.MAR.2016 10:07:46



WCDMA Band V 12.2k RMC

Lowest Channel

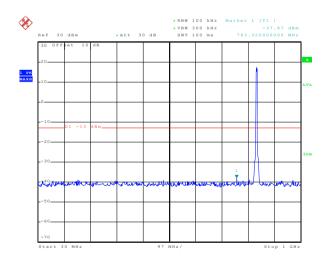


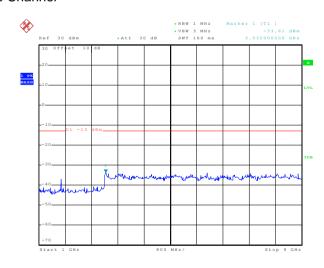


Date: 21.MAR.2016 09:27:11

30MHz~1GHz

Middle Channel



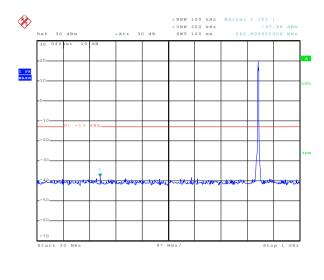


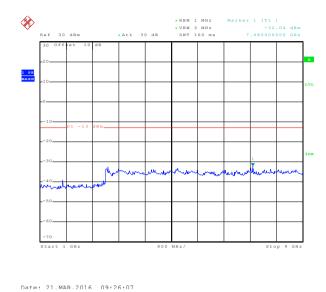
Date: 21.MAR.2016 09:27:25

30MHz~1GHz



Highest Channel





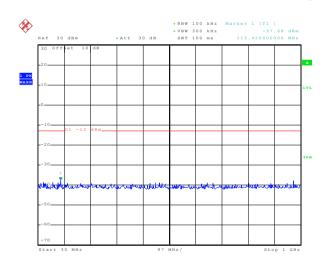
Date: 21.MAR.2016 09:27:43

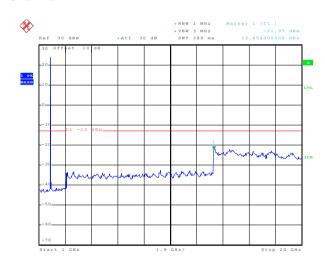
30MHz~1GHz

1GHz~9GHz

WCDMA Band II 12.2k RMC

Lowest Channel





Date: 21.MAR.2016 09:31:44

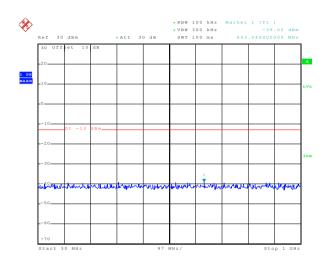
30MHz~1GHz

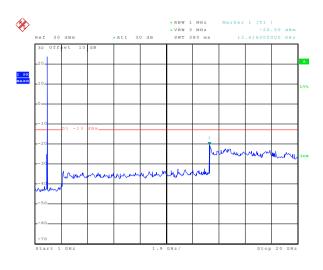
1GHz~20GHz

Date: 21.MAR.2016 09:33:14



Middle Channel

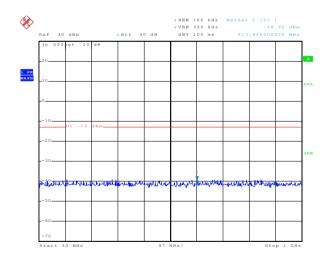


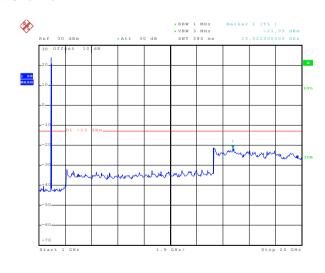


Date: 21.MAR.2016 09:31:54

30MHz~1GHz

Highest Channel





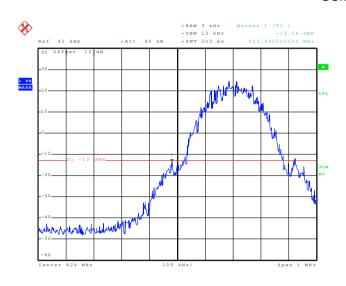
Date: 21.MAR.2016 09:32:04

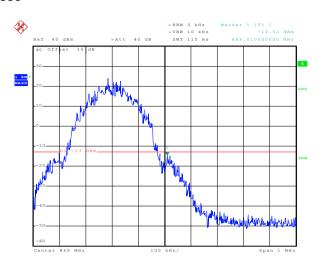
30MHz~1GHz



Band edge emission

GSM850





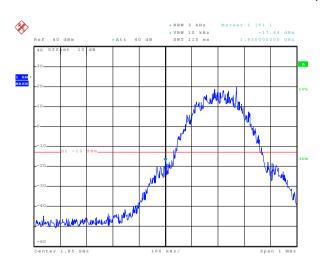
Lowest channel

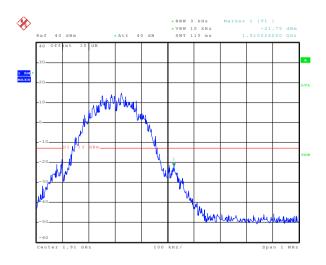
Highest channel

PCS1900

Date: 21.MAR.2016 09:47:25

Date: 21.MAR.2016 10:00:32





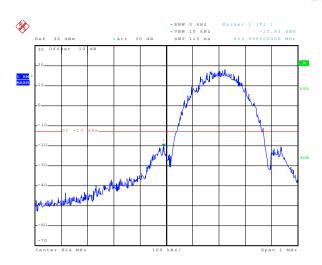
Date: 21.MAR.2016 10:00:12

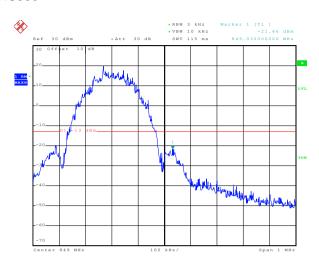
Lowest channel

Highest channel



EGPRS850



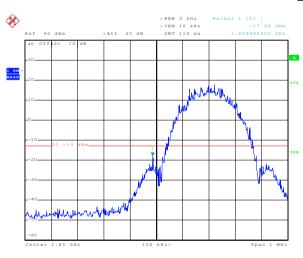


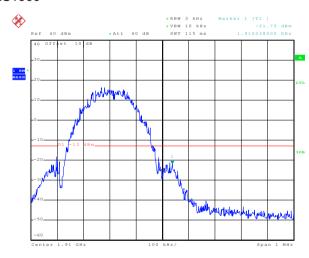
Date: 5.APR.2016 21:37:15

Lowest channel

Date: 5.APR.2016 21:38:30 Highest channel

EGPRS1900





Date: 5.APR.2016 21:59:58

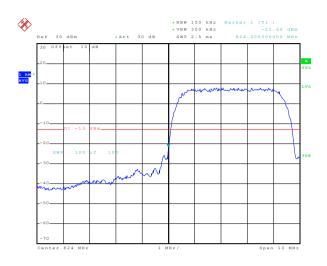
Lowest channel

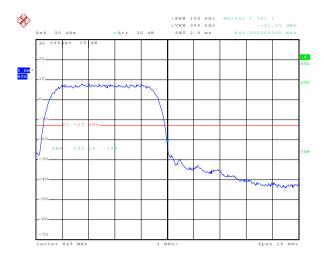
Date: 5.APR.2016 22:00:38

Highest channel



WCDMA BAND V RMC 12.2kbps





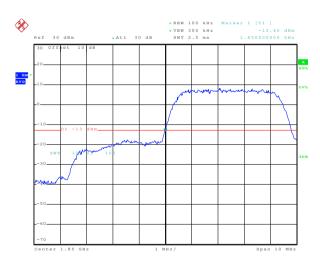
Date: 21.MAR.2016 09:24:24

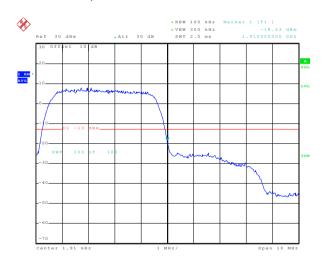
Lowest channel

Highest channel

WCDMA Band II RMC 12.2kbps

Date: 21.MAR.2016 09:24:43





Date: 21.MAR.2016 09:31:22

Lowest channel

Date: 21.MAR.2016 09:30:51

Highest channel



6.10 ERP, EIRP Measurement

Test Requirement:	FCC part 22.913(a), FCC part 24.232(b)
Test Method:	FCC part 2.1046
Limit:	GSM850 7W: ERP PCS1900 2W: EIRP WCDMA Band V: 7W ERP WCDMA Band II: 2W EIRP
Test setup:	Below 1GHz
	Antenna Tower Search Antenna Antenna Ground Plane Above 1GHz Antenna Tower Antenna Tower





Test Procedure:	1. The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer.
	 During the measurement, the EUT was communication with the station. The highest emission was recorded with the rotation of the turntable and the lowering of the test antenna from 4m to 1m. The reading was recorded and the field strength (E in dBuV/m) was calculated.
	3. ERP in frequency band 824.2 –848.80.8MHz were measured using a substitution method. The EUT was replaced by dipole antenna connected, the S.G. output was recorded and ERP was calculated as follows:
	ERP = S.G. output (dBm) + Antenna Gain (dBd) – Cable Loss (dB)
	4. EIRP in frequency band 1850.2 –1909.8MHz were measured using a substitution method. The EUT was replaced by or horn antenna connected, the S.G. output was recorded and EIRP was calculated as follows:
	EIRP = S.G. output (dBm) + Antenna Gain (dBi) - Cable Loss (dB)
	5. The worse case was relating to the conducted output power.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed (All three channels were tested, and just the worst case data were shown in the report.)

Measurement Data (worst case)





EUT mode	Channel	EUT Pol.	Antenna Pol.	ERP(dBm)	Limit (dBm)	Result	
CCMOEO	GSM850 251	Н	V	34.69			
GSIVIOSU		П	Н	30.93			
EGPRS 850	190	Ш	V	25.92	20.45	Door	
EGPRS 650		190 H	Н	Н	24.48	38.45	Pass
UMTS 850 12.2k		Ш	V	23.95			
RMC	4183	Н	Н	21.07			

EUT mode	Channel	EUT Pol.	Antenna Pol.	EIRP(dBm)	Limit (dBm)	Result		
DCS1000	CS1900 512	Н	V	24.69				
PC31900			Н	21.27				
EGPRS 1900	512	ш	ы	Н	V	23.75	33	Pass
EGPK3 1900		312	.3 1900 512	512	Н	17.88	33	Pa55
UMTS 1900	9538	Н	V	23.28				
12.2k RMC	9036	П	Н	20.88				



6.11 Field strength of spurious radiation measurement

Test Requirement:	FCC part 22.917(a), FCC part 24.238(a)
Test Method:	FCC part 2.1053
Limit:	-13dBm
Test setup:	Below 1GHz
	Antenna Tower Search Antenna RF Test Receiver Tum Table Ground Plane
	Above 1GHz
	Antenna Tower Horn Antenna Spectrum Analyzer Turn Table Amplifier
	Substituted method:
	Ground plane Antenna mast
	d: distance in meters d:3 meter S.G. Substituted Dipole or Horn Antenna Bi-Log Antenna or Horn Antenna
Test Procedure:	 The EUT was placed on an non-conductive turntable using a non-conductive support. The radiated emission at the fundamental frequency was measured at 3 m with a test antenna and EMI spectrum analyzer. During the tests, the antenna height and the EUT azimuth were varied in order to identify the maximum level of emissions from the EUT. This maximization process was repeated with the EUT positioned in each of its three orthogonal orientations.
	 The frequency range up to tenth harmonic was investigated for each of three fundamental frequency (low, middle and high channels). Once spurious emission was identified, the power of the emission was determined using the substitution method.





	The spurious emissions attenuation was calculated as the difference between radiated power at the fundamental frequency and the spurious emissions frequency. ERP / EIRP = S.G. output (dBm) + Antenna Gain(dB/dBi) – Cable Loss (dB)
Test Uncertainty:	± 4.88 dB
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details.
Test results:	Passed





Measurement Data (worst case)

Test mode:	GSM850		Test channel:	Lowest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MH2)	Polarization	Level (dBm)	Limit (dBin)		
1648.40	Vertical	-52.29	-13.00	Pass	
2472.60	V	-45.27	-13.00		
1648.40	Horizontal	-54.82	-13.00	Doog	
2472.60	Н	-44.63	-13.00	Pass	
Test mode:	GSN	1850	Test channel:	Middle	
Frequency (MHz)	Spurious	Emission		Result	
Frequency (MHZ)	Polarization	Level (dBm)	Limit (dBm)		
1673.20	Vertical	-48.05			
2509.80	V	-50.08	-13.00	Pass	
1673.20	Horizontal	-49.30			
2509.80	H	-53.38	-13.00	Pass	
Test mode:	GSN	1850	Test channel:	Highest	
Frequency (MHz)	Spurious Emission		Limit (dBm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	Limit (dbin)	Result	
1697.60	Vertical	-46.04	-13.00	Pass	
2546.40	V	-54.72	-13.00	Fa55	
1697.60	Horizontal	-49.00	12.00	Door	
2546.40	Н	-54.08	-13.00	Pass	

Remark:

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.





Test mode:	PCS1900		Test channel:	Lowest	
Fraguency (MUz)	Spurious Emission		Limit (dPm)	Decult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3700.40	Vertical	-46.35	-13.00	Pass	
3700.40	Horizontal	-46.95	-13.00	Pass	
Test mode:	PCS	1900	Test channel:	Middle	
Fraguency (MUz)	Spurious Emission		Limit (dDm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3760.00	Vertical	-46.40	-13.00	Pass	
3760.00	Horizontal	-48.81	-13.00	Pass	
Test mode:	PCS	1900	Test channel:	Highest	
Eroguopov (MHz)	Spurious Emission		Limit (dDm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3819.60	Vertical	-37.74	-13.00	Pass	
3819.60	Horizontal	-41.04	-13.00	Pass	

Remark:

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.





Test mode:	WCDMA BAND V 12.2k RMC		Test channel:	Lowest	
Fraguency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dbin)		
1652.80	Vertical	-51.44	-13.00	Pass	
2479.20	V	-54.20	-13.00	Pass	
1652.80	Horizontal	-56.09	-13.00	Pass	
2479.20	Н	-54.39	-13.00	Pass	
Test mode:	WCDMA BANI	O V 12.2k RMC	Test channel:	Middle	
Frequency (MHz)	Spurious	Emission	Limit (dPm)	Result	
Frequency (MHZ)	Polarization	Level (dBm)	Limit (dBm)		
1673.20	Vertical	-50.89	-13.00	Pass	
2509.80	V	-55.41	-13.00	F d 5 5	
1673.20	Horizontal	-52.76	-13.00	Pass	
2509.80	Н	-54.85	-13.00	Pass	
Test mode:	WCDMA BANI	O V 12.2k RMC	Test channel:	Highest	
Frequency (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (Miriz)	Polarization	Level (dBm)	Lillill (dBill)		
1693.20	Vertical	-53.79	-13.00	Door	
2539.80	V	-55.53	-13.00	Pass	
1693.20	Horizontal	-59.20	12.00	Door	
2539.80	Н	-55.08	-13.00	Pass	

Remark:

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.



Report No: CCISE160306201

Test mode:	WCDMA Band II 12.2k RMC		Test channel:	Lowest	
Fraguenov (MHz)	Spurious Emission		Limit (dPm)	Dooult	
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3704.80	Vertical	-43.92	12.00	Pass	
3704.80	Horizontal	-47.34	-13.00		
Test mode:	WCDMA Band	III 12.2k RMC	Test channel:	Middle	
Fraguenov (MHz)	Spurious	Emission	Limit (dBm)	Result	
Frequency (MHz)	Polarization	Level (dBm)			
3760.00	Vertical	-45.42	12.00	Door	
3760.00	Horizontal	-47.60	-13.00	Pass	
Test mode:	WCDMA Band	II 12.2k RMC	Test channel:	Highest	
	Spurious Emission				
Frequency (MHz)	Polarization	Level (dBm)	Limit (dBm)	Result	
3815.20	Vertical	-45.03			
3815.20	Horizontal	-46.76	-13.00	Pass	

Remark:

^{1.} The emission levels of below 1 GHz are very lower than the limit and not show in test report.



6.12 Frequency stability V.S. Temperature measurement

Test Requirement:	FCC Part 2.1055(a)(1)(b)
Test Method:	FCC Part 2.1055(a)(1)(b)
Limit:	±2.5 ppm
Test setup:	Temperature Chamber
	Spectrum analyzer Att. Variable Power Supply Note: Measurement setup for testing on Antenna connector
Test procedure:	 The equipment under test was connected to an external DC power supply and input rated voltage. RF output was connected to a frequency counter or spectrum analyzer via feed through attenuators. The EUT was placed inside the temperature chamber. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and measure EUT 25°C operating frequency as reference frequency. Turn EUT off and set the chamber temperature to −30°C. After the temperature stabilized for approximately 30 minutes recorded the frequency. Repeat step measure with 10°C increased per stage until the highest temperature of +50°C reached
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details
Test results:	Passed
Remark:	All three channels of all modulations have been tested, but only the worst channel and the worst modulation show in this test item.





Measurement Data:

easurement Data:					
Re	ference Frequency: G	SM850 Middle	channel=190 channel	el=836.6MHz	
Power supplied	Temperature (°C)	Freq	uency error	Limit (ppm)	Result
(Vdc)	remperature (C)	Hz	ppm	Limit (ppm)	Kesuit
	-30	189	0.225914		
	-20	123	0.147024		
	-10	150	0.179297		
	0	144	0.172125		
3.80	10	165	0.197227	±2.5	Pass
	20	120	0.143438		
	30	128	0.153000		
	40	117	0.139852		
	50	109	0.130289		
Re	ference Frequency: PO	CS1900 Middle	channel=661 chann	el=1880MHz	
Power supplied	Tamanaratura (°C)	Frequency error		Limit (mmm)	Dogult.
(Vdc)	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	165	0.087766		
	-20	123	0.065426		
	-10	120	0.063830		
	0	134	0.071277		
3.80	10	136	0.072340	±2.5	Pass
	20	144	0.076596		
	30	102	0.054255]	
	40	118	0.062766	1	
	50	109	0.057979		





Power supplied	Temperature (°C)	Frequency error		1	- ·
(Vdc)		Hz	ppm	Limit (ppm)	Result
3.80	-30	187	0.223524	±2.5	Pass
	-20	145	0.173321		
	-10	165	0.197227		
	0	174	0.207985		
	10	122	0.145828		
	20	130	0.155391		
	30	136	0.162563		
	40	117	0.139852		
	50	108	0.129094		
Refe	erence Frequency: EGF	PRS 1900 Mide	dle channel=661 cha	nnel=1880MHz	
Power supplied (Vdc)	Temperature (°C)	Frequency error		Limit (nnm)	Result
		Hz	ppm	Limit (ppm)	Result
	-30	165	0.087766	±2.5	Pass
	-20	123	0.065426		
	-10	142	0.075532		
	0	151	0.080319		
3.80	10	158	0.084043		
	20	133	0.070745		
	30	139	0.073936		
	40	107	0.056915		
	50	104	0.055319		





Power supplied (Vdc)	Temperature (°C)	Frequency error			
		Hz	ppm	Limit (ppm)	Result
	-30	198	0.236672	±2.5	Pass
	-20	165	0.197227		
	-10	187	0.223524		
	0	174	0.207985		
3.80	10	123	0.147024		
	20	130	0.155391		
	30	142	0.169735		
	40	127	0.151805		
	50	107	0.127899		
Reference Fr	equency: WCDMA BA	ND II 12.2k	RMC Middle channel=9	9400 channel=18	80MHz
Power supplied (Vdc)	Fre		equency error	Limit (mmm)	Danult
	Temperature (°C)	Hz	ppm	Limit (ppm)	Result
	-30	165	0.087766	±2.5	Pass
	-20	142	0.075532		
3.80	-10	112	0.059574		
	0	107	0.056915		
	10	123	0.065426		
	20	134	0.071277		
	30	130	0.069149		
	40	149	0.079255		
	50	101	0.053723		



6.13 Frequency stability V.S. Voltage measurement

Test Requirement:	FCC Part 2.1055(d)(1)(2)
Test Method:	FCC Part 2.1055(d)(1)(2)
Limit:	±2.5ppm
Test setup:	Temperature Chamber
	Spectrum analyzer Att. Variable Power Supply Note: Measurement setup for testing on Antenna connector
Test procedure:	 Set chamber temperature to 25°C. Use a variable DC power source to power the EUT and set the voltage to rated voltage. Set the spectrum analyzer RBW low enough to obtain the desired frequency resolution and recorded the frequency. Reduce the input voltage to specify extreme voltage variation (+/-15%) and endpoint, record the maximum frequency change.
Test Instruments:	Refer to section 5.8 for details
Test mode:	Refer to section 5.3 for details, and all channels have been tested, only shows the worst channel data in this report.
Test results:	Passed

Measurement Data (the worst channel):





Reid	erence Frequency: G	SM850 Middle	channel=190 chanr	nel=836.6MHz	
Temperature (°C)	Power supplied (Vdc)	Frequ Hz	iency error ppm	Limit (ppm)	Result
25	4.37	65	0.077695	±2.5	Pass
	3.80	47	0.056180		
	3.23	81	0.096820		
Refe	erence Frequency: Po	CS1900 Middle	channel=661 chan	nel=1880MHz	
Temperature (°C)	Power supplied	Frequ Hz	iency error	Limit (ppm)	Result
25	(Vdc) 4.37	98	ppm 0.052128		
	3.80	68	0.036170	±2.5	Pass
25	3.23	74	0.039362	±2.5	FdSS
Refere	ence Frequency: EGF			nnel=836.6MHz	
Temperature (℃)	Power supplied		iency error	Limit (ppm)	Result
	(Vdc) 4.37	Hz	ppm 0.105188		
		88		_	Pass
25	3.80	54	0.064547	©±2.5	
D (3.23	63	0.075305	1.40001411	
Refere	nce Frequency: EGP			annel=1880MHz	
Temperature (°C)	Power supplied (Vdc)				
remperature (C)	(Vdc)		ency error	Limit (ppm)	Result
remperature (C)		Hz 66	ppm 0.035106	Limit (ppm)	Result
remperature (C)	(Vdc)	Hz	ppm	Limit (ppm) ±2.5	Result Pass
	(Vdc) 4.37	Hz 66	ppm 0.035106	_	
25	(Vdc) 4.37 3.80	Hz 66 48 74	ppm 0.035106 0.025532 0.039362	±2.5	Pass
25 Reference F	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied	Hz 66 48 74) 12.2k RMC M Frequ	ppm 0.035106 0.025532 0.039362 iddle channel=4183	±2.5 3 channel=836.6N	Pass
25	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied (Vdc)	Hz 66 48 74 0 12.2k RMC M Frequ	ppm 0.035106 0.025532 0.039362 iddle channel=4183 ency error ppm	±2.5	Pass
25 Reference F Temperature (°C)	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied (Vdc) 4.37	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85	ppm 0.035106 0.025532 0.039362 iddle channel=4183 ency error ppm 0.101602	±2.5 3 channel=836.6N Limit (ppm)	Pass //Hz Result
25 Reference F	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied (Vdc) 4.37 3.80	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47	ppm 0.035106 0.025532 0.039362 iddle channel=4183 ency error ppm 0.101602 0.056180	±2.5 3 channel=836.6N	Pass
Reference F Temperature (°C)	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied (Vdc) 4.37 3.80 3.23	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47 95	ppm 0.035106 0.025532 0.039362 iddle channel=4183 ency error ppm 0.101602 0.056180 0.113555	±2.5 3 channel=836.6N Limit (ppm) ±2.5	Pass //Hz Result Pass
25 Reference F Temperature (°C) 25 Reference F	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 Power supplied (Vdc) 4.37 3.80	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47 95	ppm 0.035106 0.025532 0.039362 iddle channel=4183 ency error ppm 0.101602 0.056180 0.113555	±2.5 B channel=836.6N Limit (ppm) ±2.5 0 channel=1880N	Pass MHz Result Pass
Reference F Temperature (°C)	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 (Vdc) 4.37 3.80 3.23 Frequency: UMTS 190	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47 95	ppm 0.035106 0.025532 0.039362 iddle channel=4183 iency error ppm 0.101602 0.056180 0.113555 Middle channel=940	±2.5 3 channel=836.6N Limit (ppm) ±2.5	Pass //Hz Result Pass
25 Reference F Temperature (°C) 25 Reference F	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 (Vdc) 4.37 3.80 3.23 Frequency: UMTS 190 Power supplied	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47 95 00 12.2k RMC M	ppm 0.035106 0.025532 0.039362 iddle channel=4183 iency error ppm 0.101602 0.056180 0.113555 Middle channel=940 iency error	±2.5 B channel=836.6N Limit (ppm) ±2.5 0 channel=1880N	Pass MHz Result Pass
25 Reference F Temperature (°C) 25 Reference F	(Vdc) 4.37 3.80 3.23 Frequency: UMTS 850 (Vdc) 4.37 3.80 3.23 Frequency: UMTS 190 Power supplied (Vdc)	Hz 66 48 74 0 12.2k RMC M Frequ Hz 85 47 95 00 12.2k RMC M Frequ Hz	ppm 0.035106 0.025532 0.039362 iddle channel=4183 iency error ppm 0.101602 0.056180 0.113555 Middle channel=940 iency error ppm	±2.5 B channel=836.6N Limit (ppm) ±2.5 0 channel=1880N	Pass MHz Result Pass